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April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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HA1630Q01/02/03 Series

Low Voltage Operation CMOS Quad Operational Amplifier

REJ03D0802-0100

Rev.1.00

Mar 10, 2006

Description

The HA1630Q01/02/03 are dual CMOS Operational Amplifiers realizing low voltage operation, low input offset voltage and low supply current. In addition to a low operating voltage from 1.8V, these device output can achieve full swing output voltage capability extending to either supply. Available in an ultra-small TSSOP-14 package that occupies only 1/2 the area of the SOP-14 package.

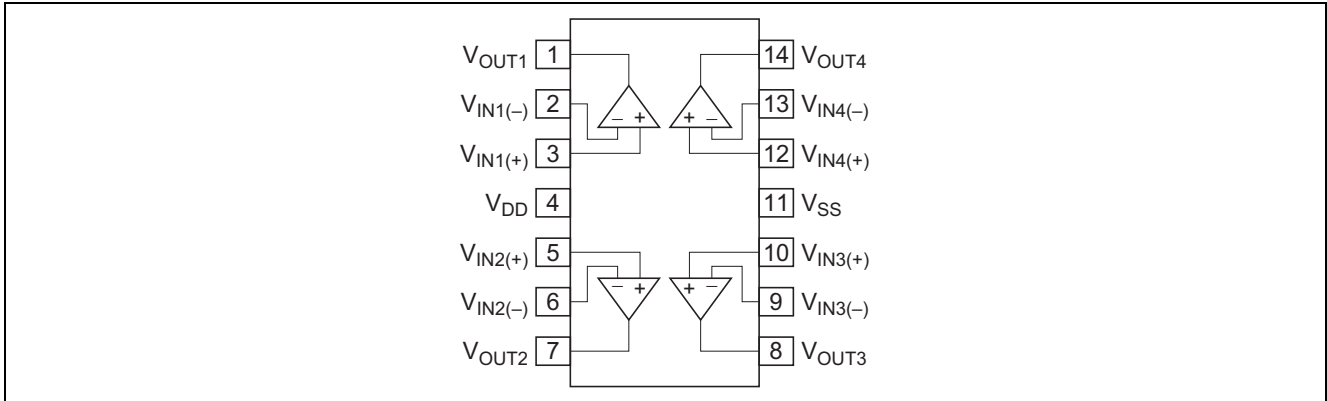
Features

- Low power and single supply operation $V_{DD} = 1.8$ to 5.5 V
- Low input offset voltage $V_{IO} = 4.0$ mV Max
- Low supply current (per channel)
 - $I_{DD} = 15$ μ A Typ (HA1630Q01)
 - $I_{DD} = 50$ μ A Typ (HA1630Q02)
 - $I_{DD} = 100$ μ A Typ (HA1630Q03)
- Maximum output voltage $V_{OH} = 2.9$ V Min (at $V_{DD} = 3.0$ V)
- Low input bias current $I_{IB} = 1$ pA Typ

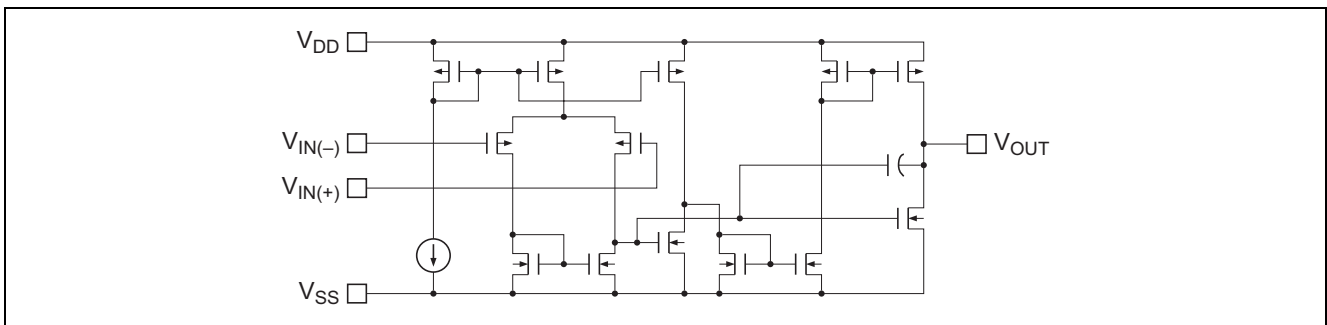
Ordering Information

| Type No. | Package Name | Package Code |
|------------|--------------|--------------|
| HA1630Q01T | TTP-14D | PTSP0014JA-B |
| HA1630Q02T | TTP-14D | PTSP0014JA-B |
| HA1630Q03T | TTP-14D | PTSP0014JA-B |

Pin Arrangement



Equivalent Circuit (per one channel)



Absolute Maximum Ratings

(Ta = 25°C)

| Items | Symbol | Ratings | Unit | Note |
|----------------------------|-----------------------|--------------------------------------|------|------|
| Supply voltage | V _{DD} | 7 | V | |
| Differential input voltage | V _{IN(diff)} | -V _{DD} to +V _{DD} | V | |
| Input voltage | V _{IN} | -0.3 to +V _{DD} | V | 1 |
| Power dissipation | P _T | 400 | mW | |
| Operating temp. Range | Topr | -40 to +85 | °C | |
| Storage temp. Range | Tstg | -55 to +125 | °C | |

Note: 1. Do not apply Input Voltage exceeding V_{DD} or 7 V.

Electrical Characteristics

(V_{DD} = 3.0 V, Ta = 25°C)

| Items | Symbol | Min | Typ | Max | Unit | Test Condition |
|---------------------------------|-----------------------|-------------|---------|-----|------|-------------------------------------|
| Input offset voltage | V _{IO} | — | — | 4.0 | mV | V _{in} = 1.5 V |
| Input offset current | I _{IO} | — | (1.0) | — | pA | V _{in} = 1.5 V |
| Input bias current | I _{IB} | — | (1.0) | — | pA | V _{in} = 1.5 V |
| Output high voltage | V _{OH} | 2.9 | — | — | V | R _L = 1 MΩ |
| Output source current | I _{O SOURCE} | 6 | 12 | — | μA | V _{OH} = 2.5 V (HA1630Q01) |
| | | 25 | 50 | — | | V _{OH} = 2.5 V (HA1630Q02) |
| | | 50 | 100 | — | | V _{OH} = 2.5 V (HA1630Q03) |
| Output low voltage | V _{OL} | — | — | 0.1 | V | R _L = 1 MΩ |
| Output sink current | I _{O SINK} | — | (0.8) | — | mA | V _{OL} = 0.5 V (HA1630Q01) |
| | | — | (1.0) | — | | V _{OL} = 0.5 V (HA1630Q02) |
| | | — | (1.2) | — | | V _{OL} = 0.5 V (HA1630Q03) |
| Common mode input voltage range | V _{CM} | -0.1 to 2.1 | — | — | V | |
| Slew rate | SR | — | (0.125) | — | V/μs | C _L = 20 pF (HA1630Q01) |
| | | — | (0.50) | — | | C _L = 20 pF (HA1630Q02) |
| | | — | (1.00) | — | | C _L = 20 pF (HA1630Q03) |
| Voltage gain | A _V | 60 | 80 | — | dB | |
| Gain bandwidth product | BW | — | (200) | — | kHz | C _L = 20 pF (HA1630Q01) |
| | | — | (680) | — | | C _L = 20 pF (HA1630Q02) |
| | | — | (1200) | — | | C _L = 20 pF (HA1630Q03) |
| Power supply rejection ratio | PSRR | 60 | 80 | — | dB | |
| Common mode rejection ratio | CMRR | 60 | 80 | — | dB | |
| Supply current | I _{DD} | — | 60 | 120 | μA | R _L = ∞ (HA1630Q01) |
| | | — | 200 | 400 | | R _L = ∞ (HA1630Q02) |
| | | — | 400 | 800 | | R _L = ∞ (HA1630Q03) |

Note: 1. () : Design specification

Table of Graphs

| Electrical Characteristics | | | HA1630Q01 Figure | HA1630Q02 Figure | HA1630Q03 Figure | Test Circuit |
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| Supply current | I_{DD} | vs Supply voltage | 1-1 | 2-1 | 3-1 | 2 |
| | | vs Ambient temperature | 1-2 | 2-2 | 3-2 | |
| Output high voltage | V_{OH} | vs Output source current | 1-3 | 2-3 | 3-3 | 4 |
| | | vs Supply voltage | 1-4 | 2-4 | 3-4 | |
| Output source current | $I_{O\ SOURCE}$ | vs Ambient temperature | 1-5 | 2-5 | 3-5 | 6 |
| Output low voltage | V_{OL} | vs Output sink current | 1-6 | 2-6 | 3-6 | 5 |
| Output sink current | $I_{O\ SINK}$ | vs Ambient temperature | 1-7 | 2-7 | 3-7 | 6 |
| Input offset voltage | V_{IO} | Distribution | 1-8 | 2-8 | 3-8 | 1 |
| | | vs Supply voltage | 1-9 | 2-9 | 3-9 | |
| | | vs Ambient temperature | 1-10 | 2-10 | 3-10 | |
| Common mode input voltage range | V_{CM} | vs Ambient temperature | 1-11 | 2-11 | 3-11 | 7 |
| Power supply rejection ratio | PSRR | vs Frequency | 1-12 | 2-12 | 3-12 | 1 |
| Common mode rejection ratio | CMRR | vs Frequency | 1-13 | 2-13 | 3-13 | 7 |
| Voltage gain & phase angle | A_V | vs Frequency | 1-14 | 2-14 | 3-14 | 10 |
| Input bias current | I_{IB} | vs Ambient temperature | 1-15 | 2-15 | 3-15 | 3 |
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| Slew Rate (rising) | SRr | vs Ambient temperature | 1-17 | 2-17 | 3-17 | 9 |
| Slew Rate (falling) | SRf | vs Ambient temperature | 1-18 | 2-18 | 3-18 | |
| Slew rate | | Large signal transient response | 1-19 | 2-19 | 3-19 | |
| | | Small signal transient response | 1-20 | 2-20 | 3-20 | |
| Total harmonic distortion + noise | (0 dB) | vs. Output voltage p-p | — | 2-21 | 3-21 | 8 |
| | (40 dB) | vs. Output voltage p-p | — | 2-22 | 3-22 | |
| Maximum p-p output voltage | | vs Frequency | 1-21 | 2-23 | 3-23 | |
| Voltage noise density | | vs Frequency | 1-22 | 2-24 | 3-24 | |

Main Characteristics (HA1630Q01)

Figure 1-1. HA1630Q01
Supply Current vs. Supply Voltage

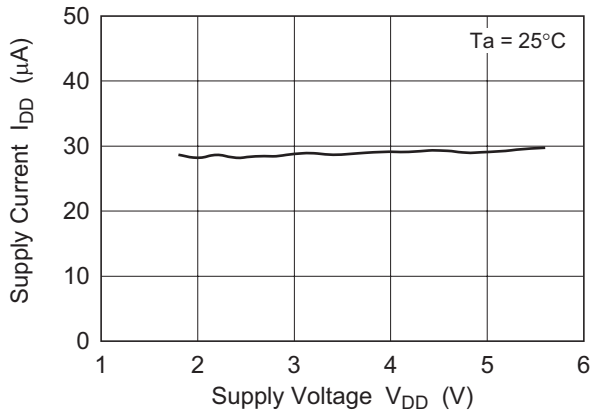


Figure 1-2. HA1630Q01
Supply Current vs. Ambient Temperature

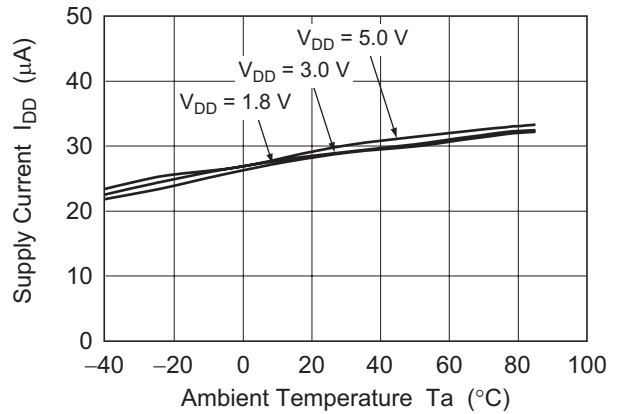


Figure 1-3. HA1630Q01
Output High Voltage vs. Output Source Current

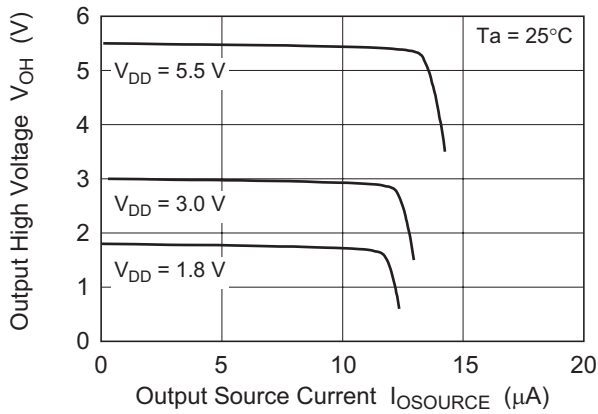


Figure 1-4. HA1630Q01
Output High Voltage vs. Supply Voltage

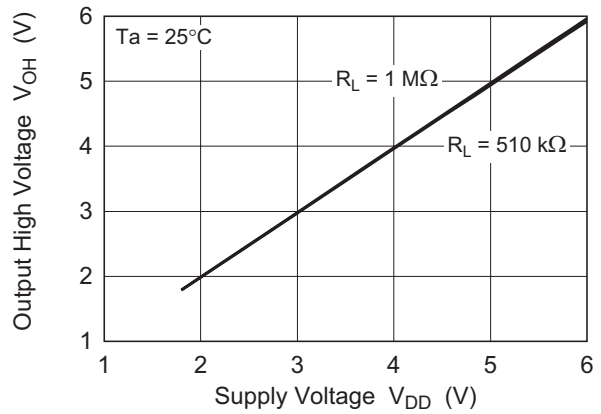
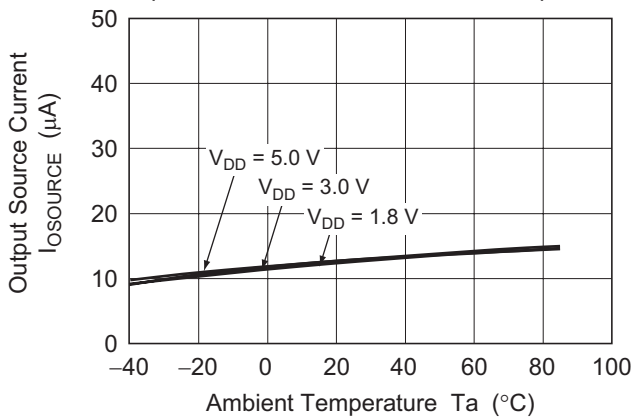


Figure 1-5. HA1630Q01
Output Source Current vs. Ambient Temperature



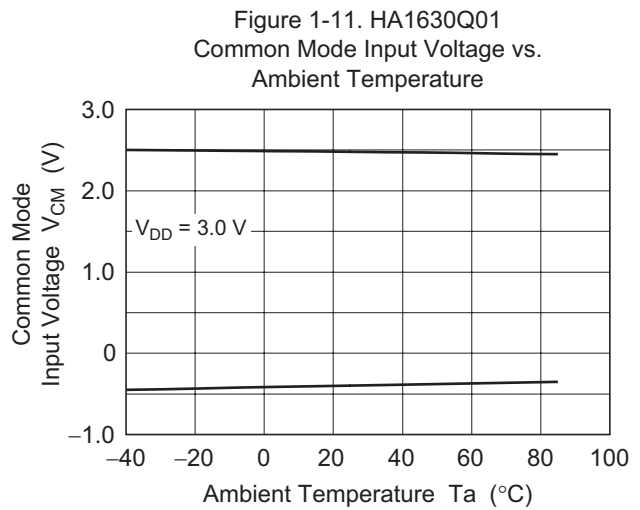
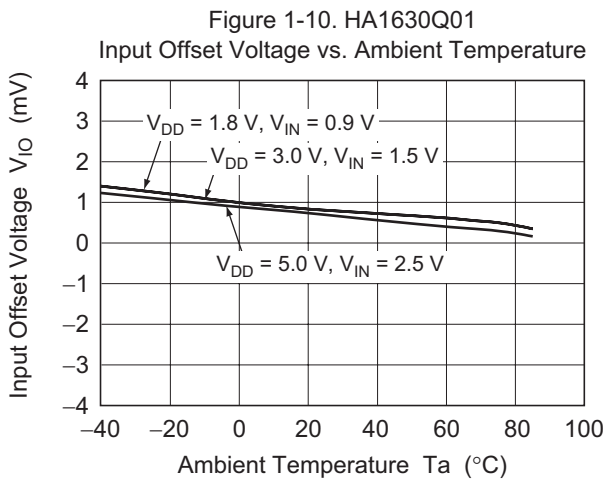
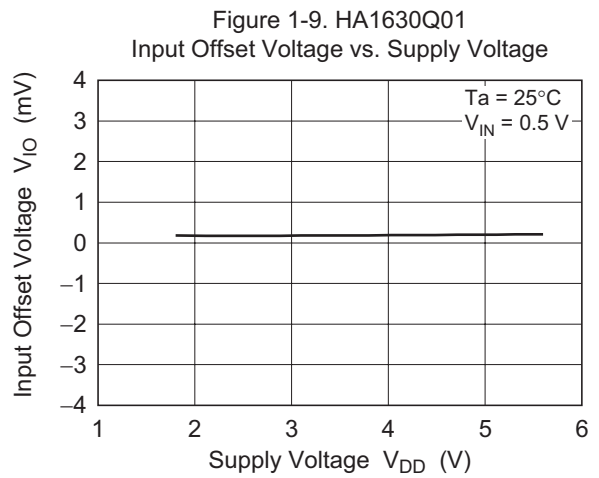
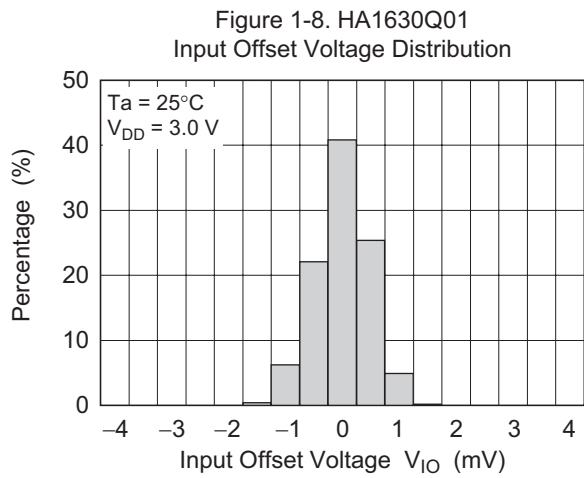
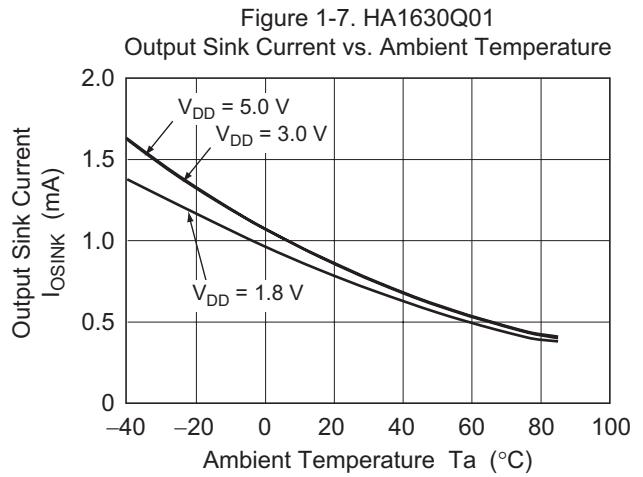
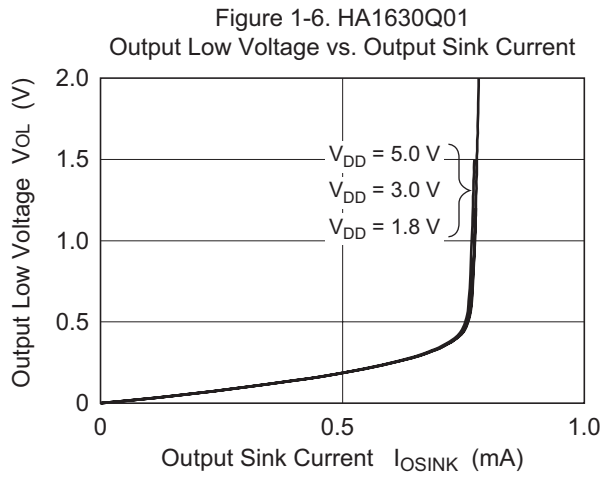


Figure 1-12. HA1630Q01
Power Supply Rejection Ratio vs. Frequency

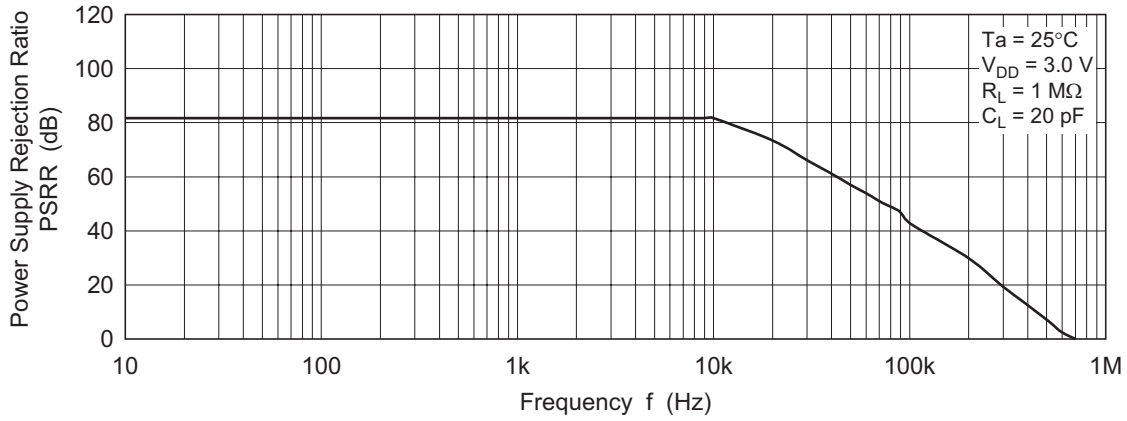


Figure 1-13. HA1630Q01
Common Mode Rejection Ratio vs. Frequency

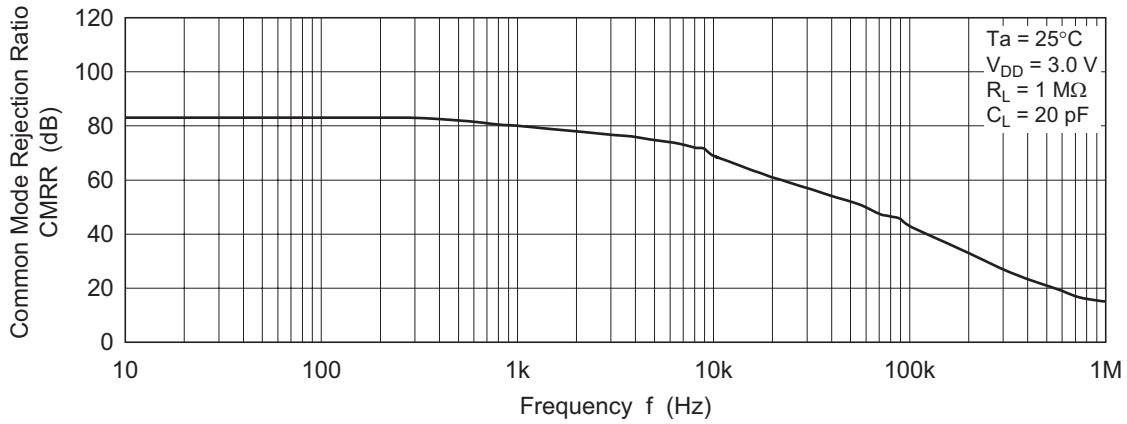
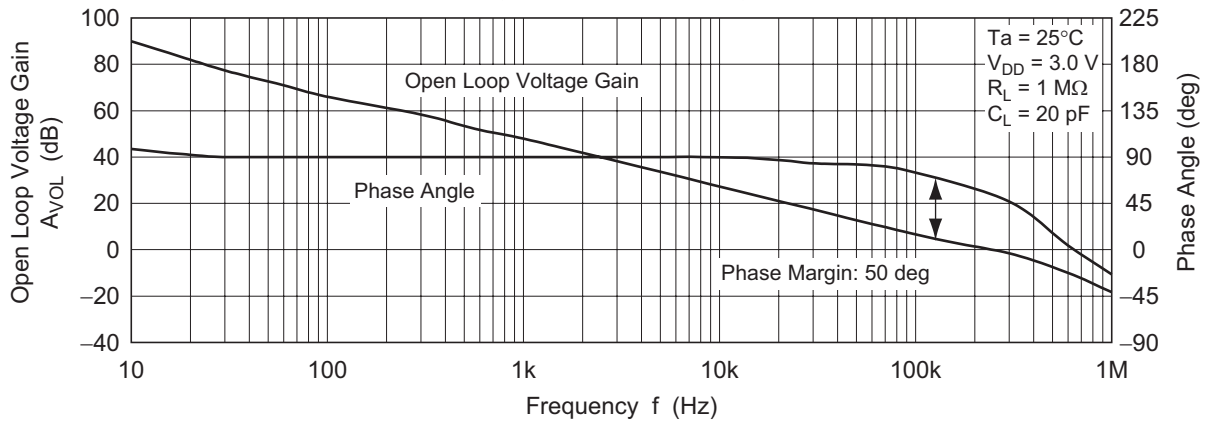


Figure 1-14. HA1630Q01
Open Loop Voltage Gain and Phase Angle vs. Frequency



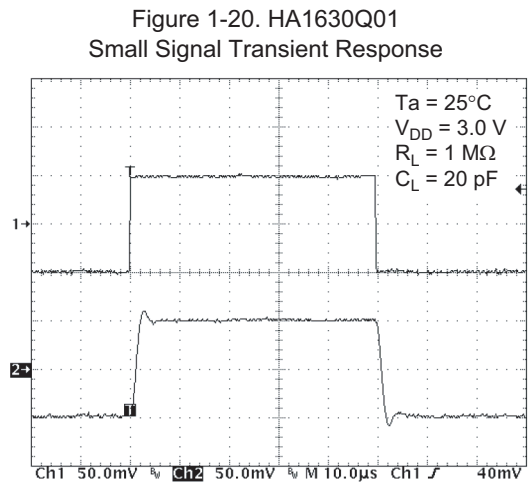
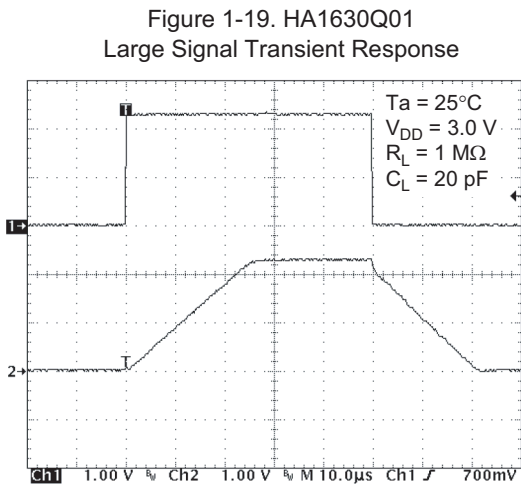
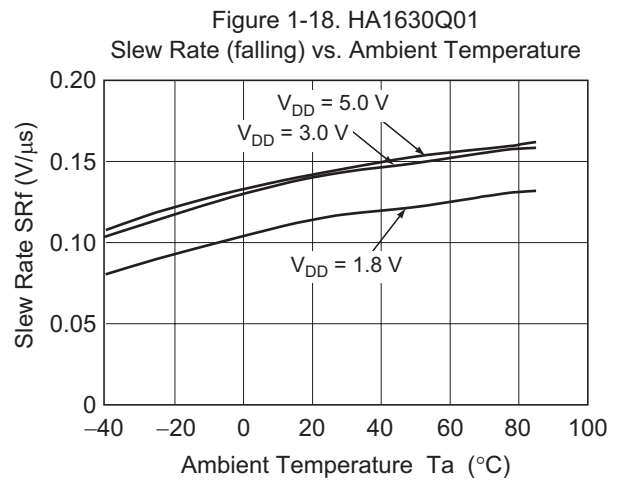
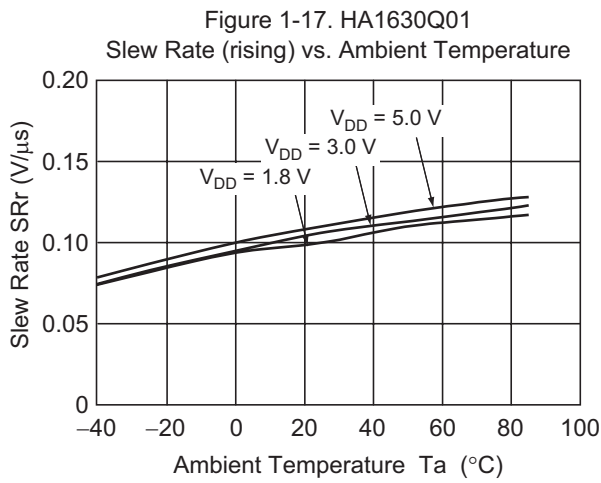
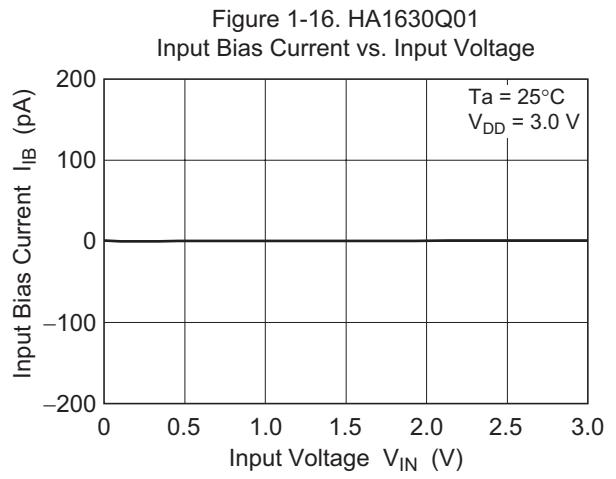
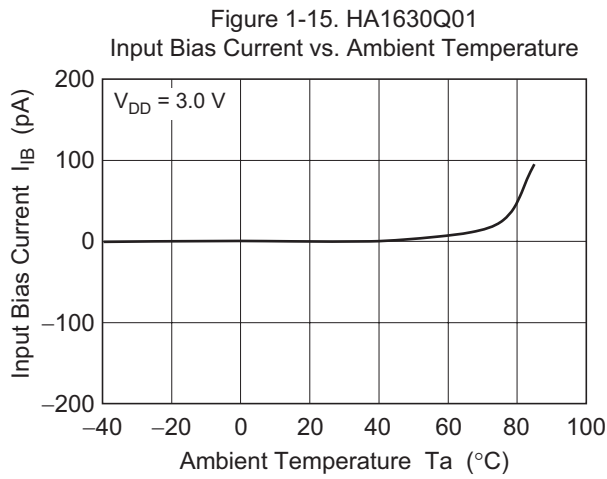


Figure 1-21. HA1630Q01
Voltage Output p-p vs. Frequency

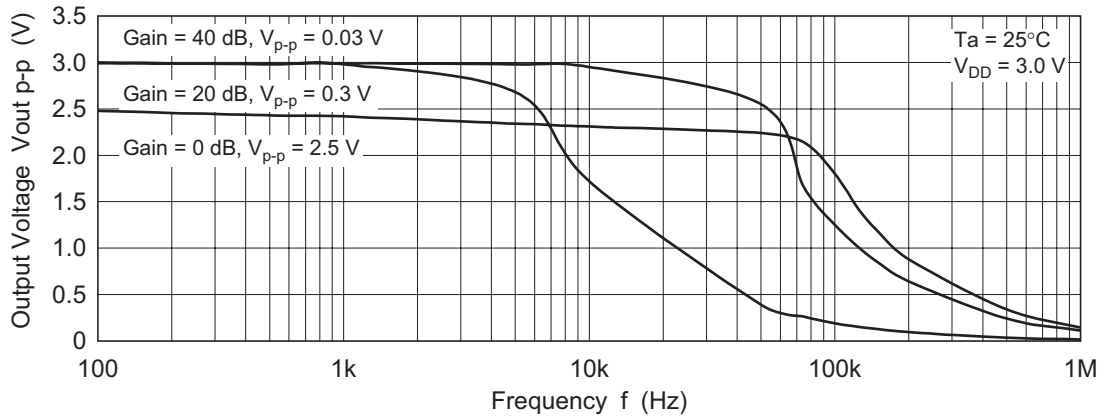
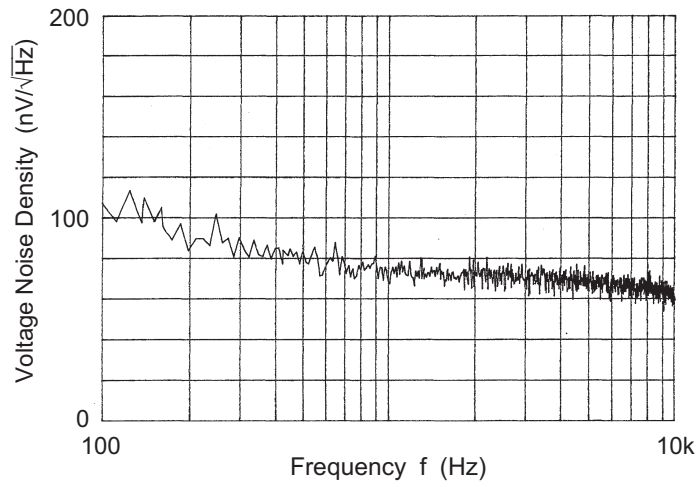


Figure 1-22. HA1630Q01
Voltage Noise Density vs. Frequency



Main Characteristics (HA1630Q02)

Figure 2-1. HA1630Q02
Supply Current vs. Supply Voltage

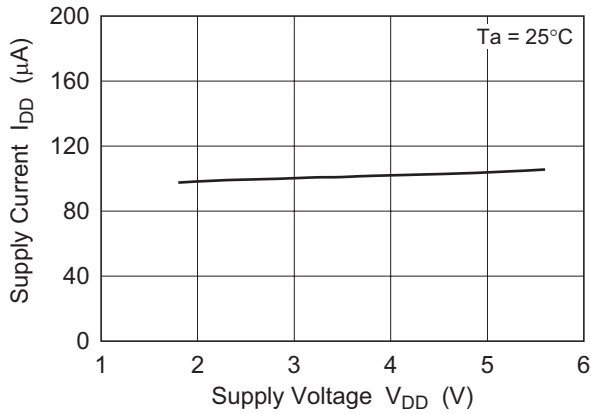


Figure 2-2. HA1630Q02
Supply Current vs. Ambient Temperature

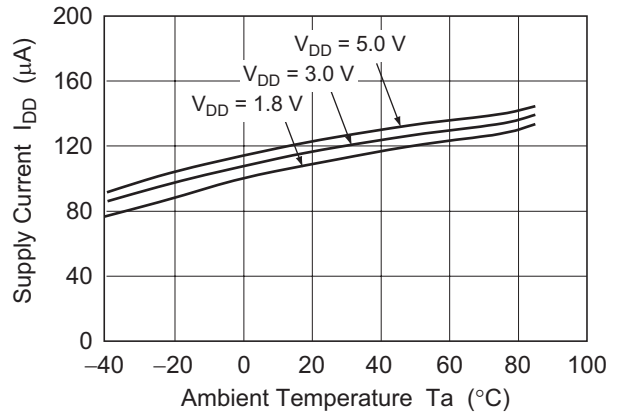


Figure 2-3. HA1630Q02
Output High Voltage vs. Output Source Current

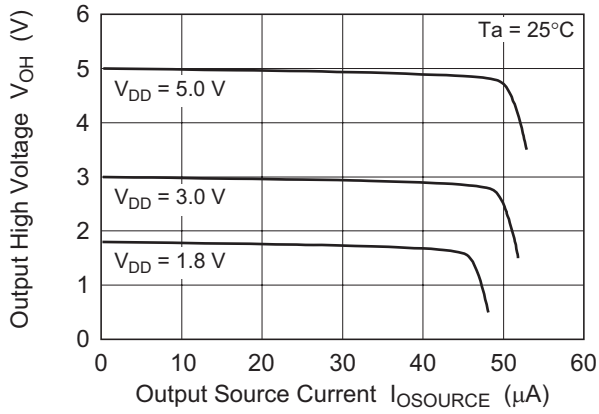


Figure 2-4. HA1630Q02
Output High Voltage vs. Supply Voltage

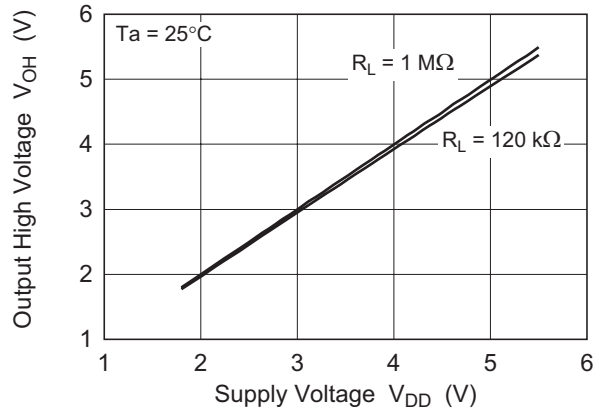
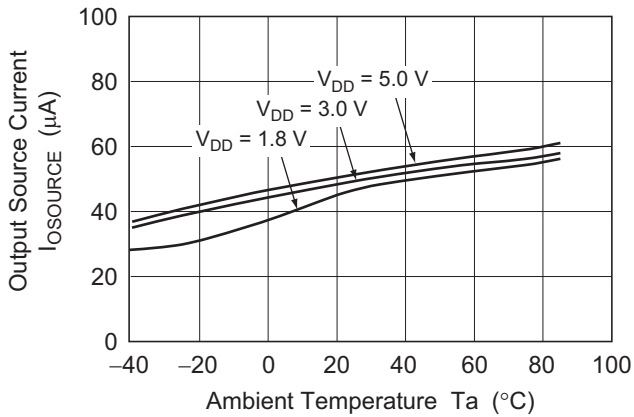


Figure 2-5. HA1630Q02
Output Source Current vs. Ambient Temperature



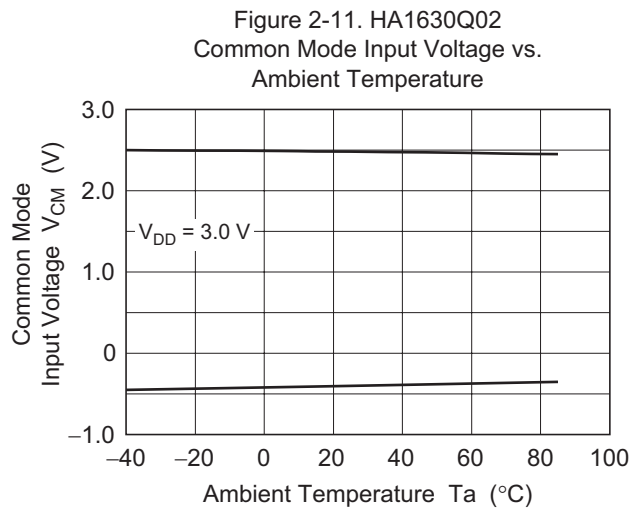
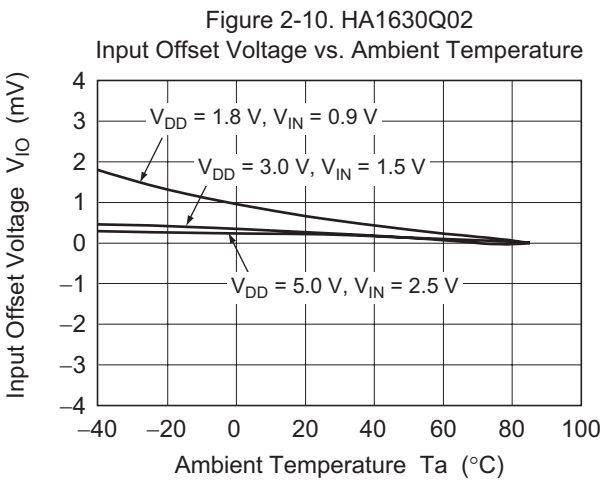
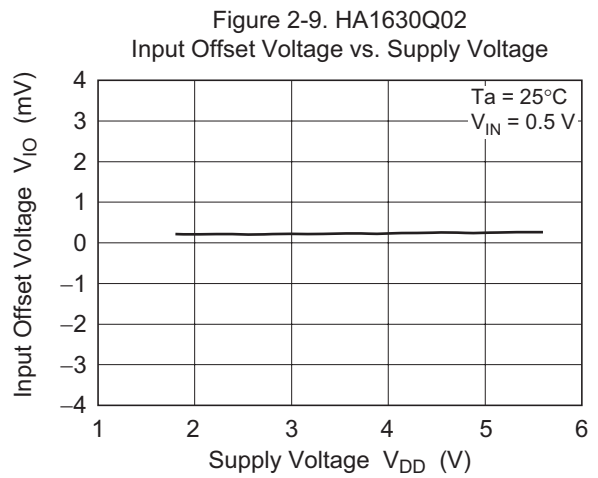
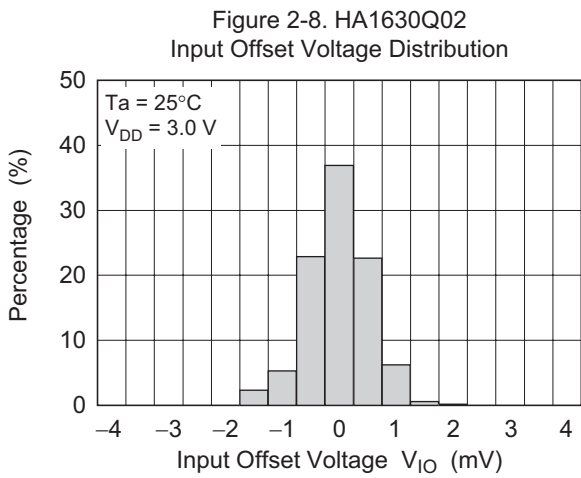
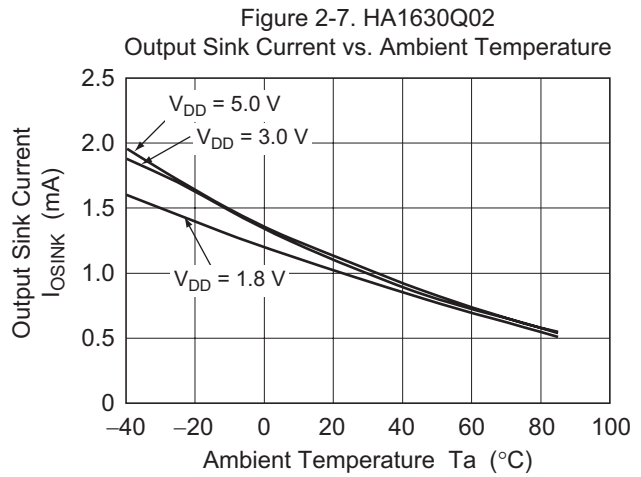
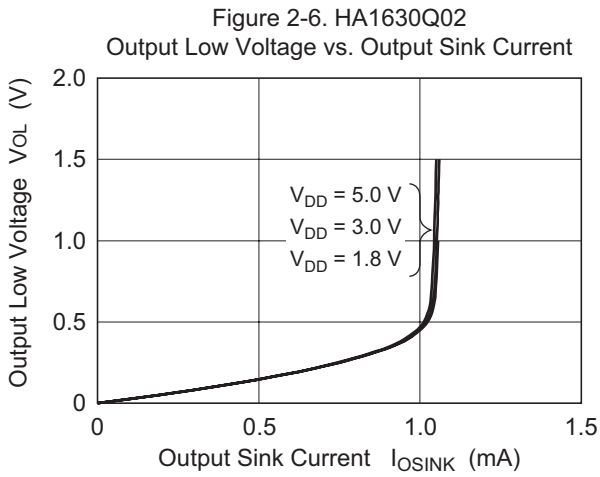


Figure 2-12. HA1630Q02
Power Supply Rejection Ratio vs. Frequency

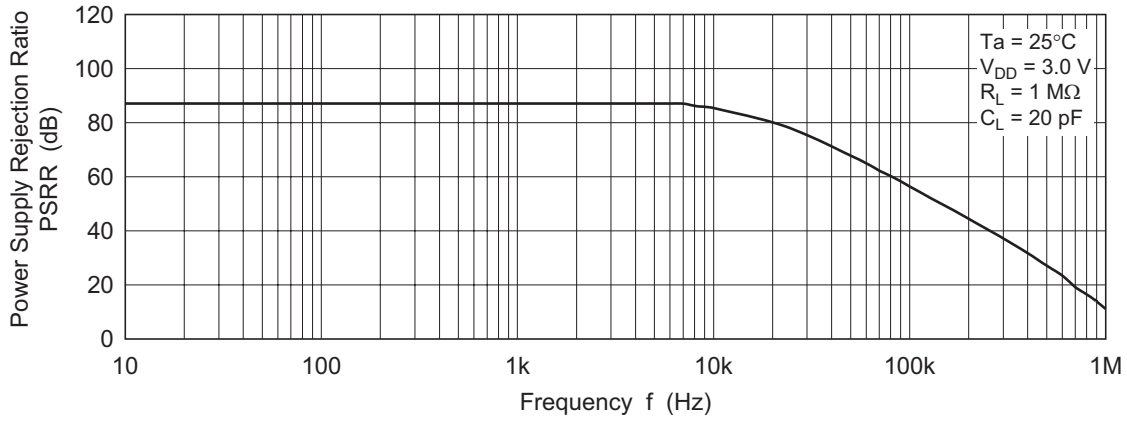


Figure 2-13. HA1630Q02
Common Mode Rejection Ratio vs. Frequency

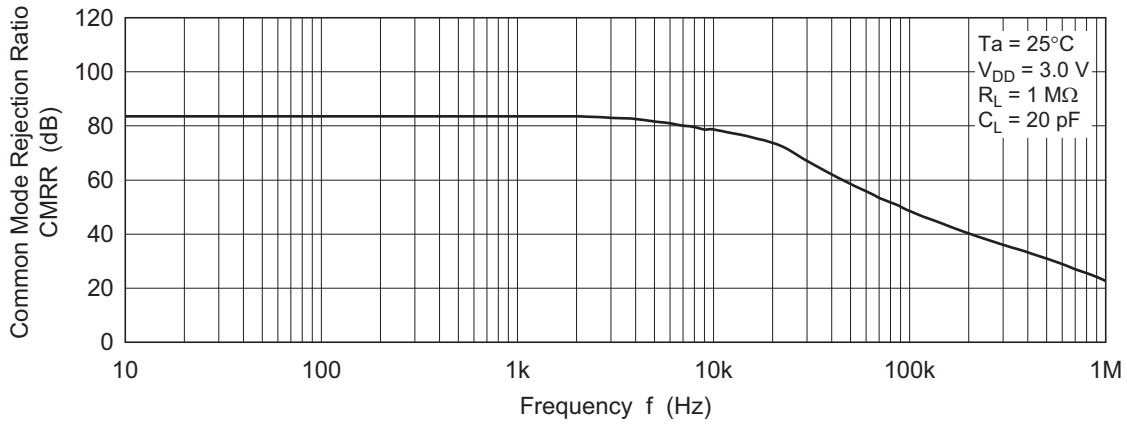
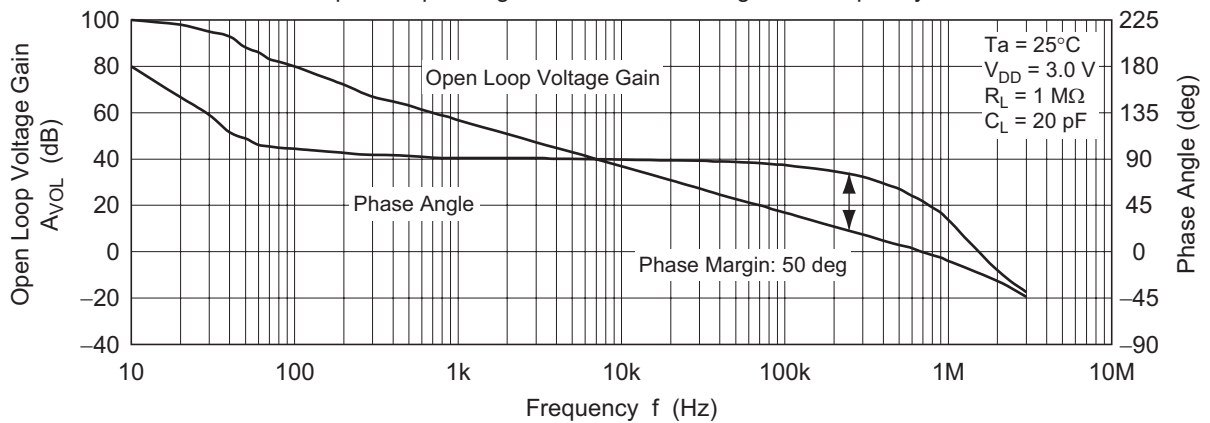


Figure 2-14. HA1630Q02
Open Loop Voltage Gain and Phase Angle vs. Frequency



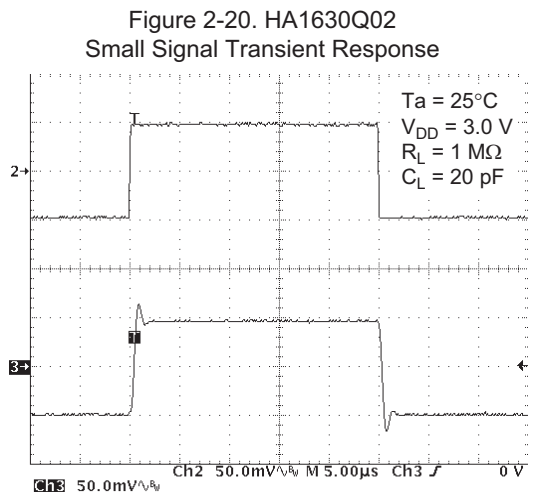
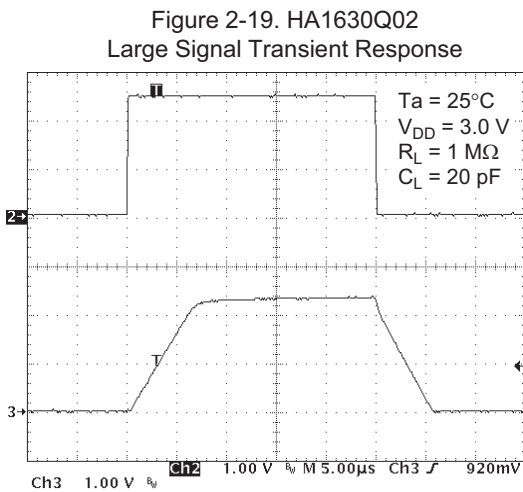
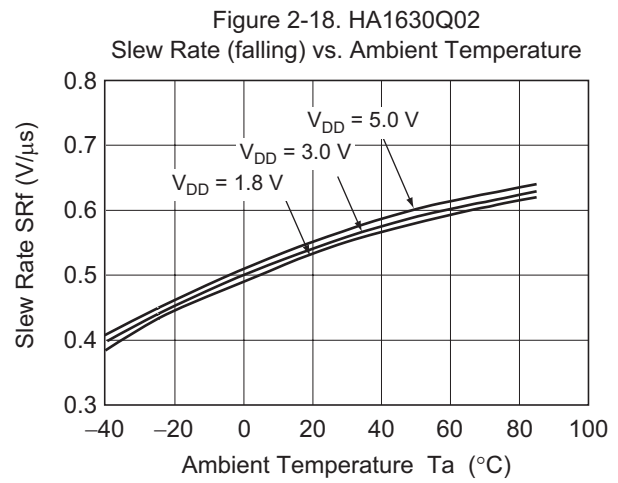
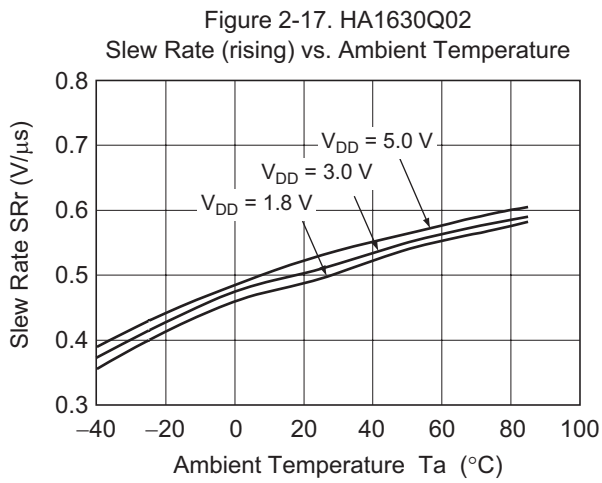
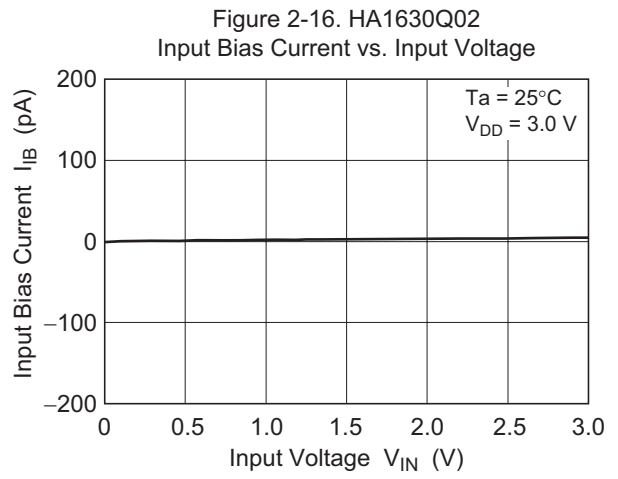
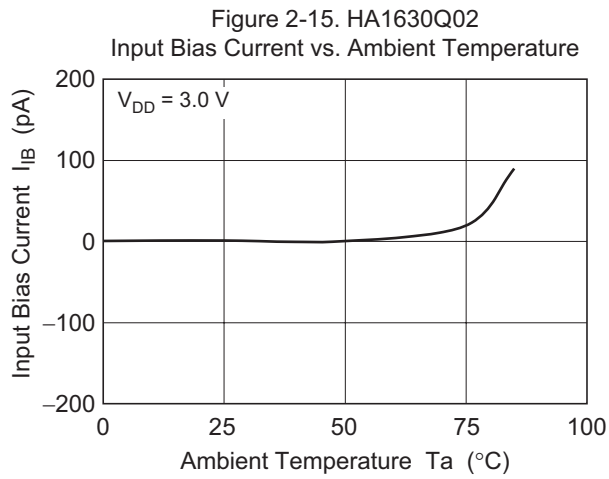


Figure 2-21. HA1630Q02
Total Harmonic Distortion + Noise vs.
Output Voltage p-p

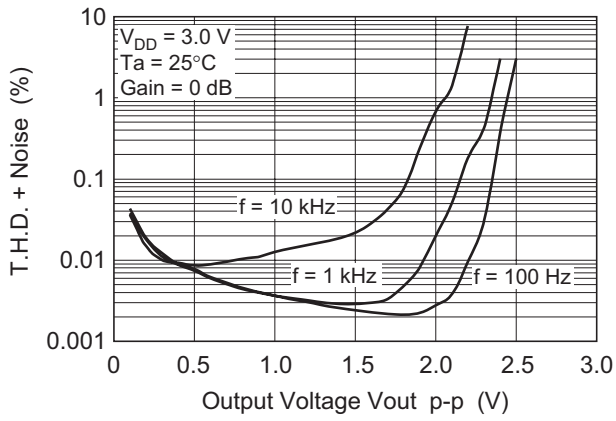


Figure 2-22. HA1630Q02
Total Harmonic Distortion + Noise vs.
Output Voltage p-p

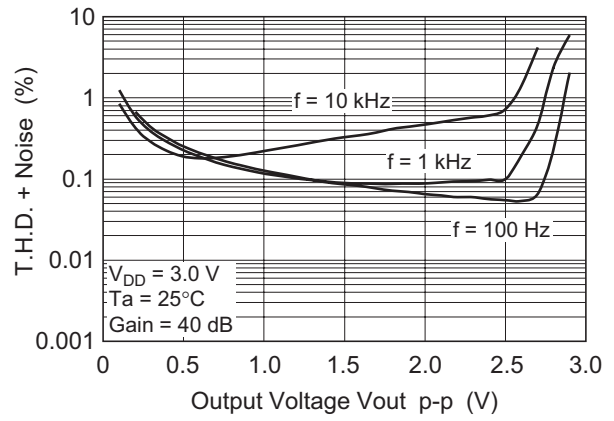


Figure 2-23. HA1630Q02
Voltage Output p-p vs. Frequency

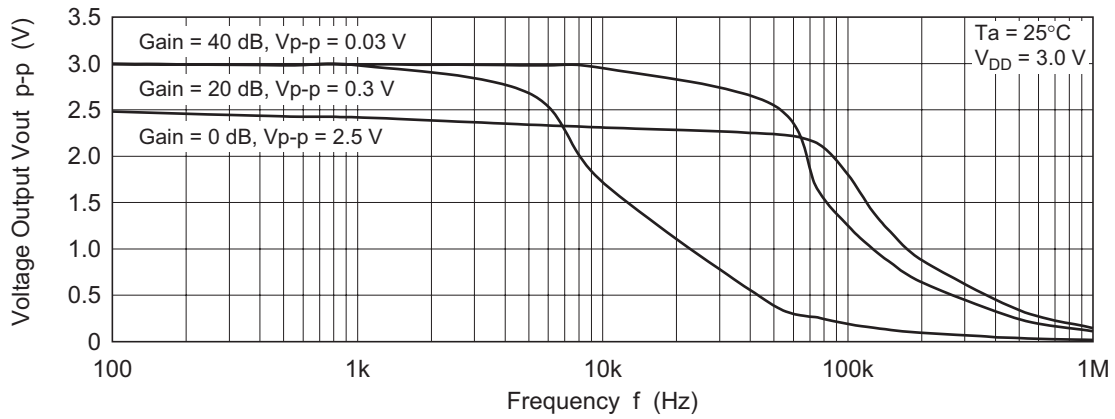
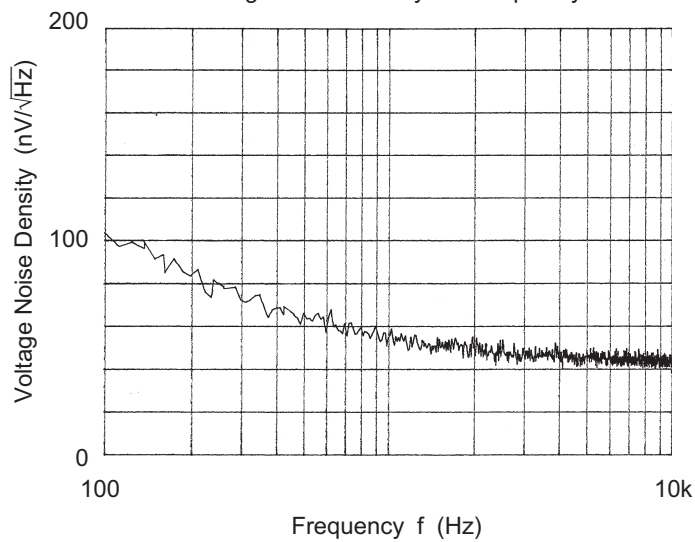
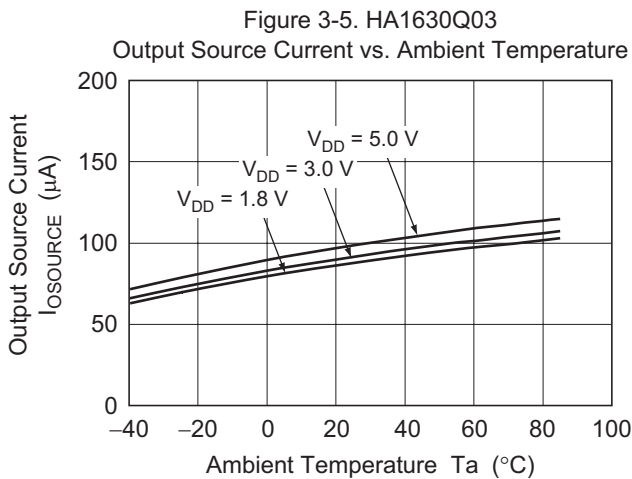
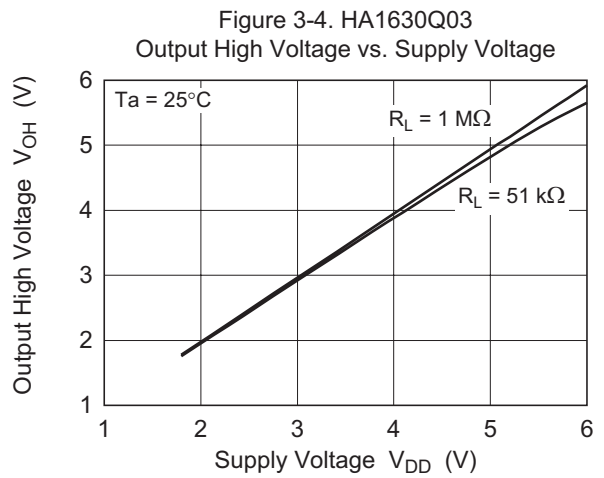
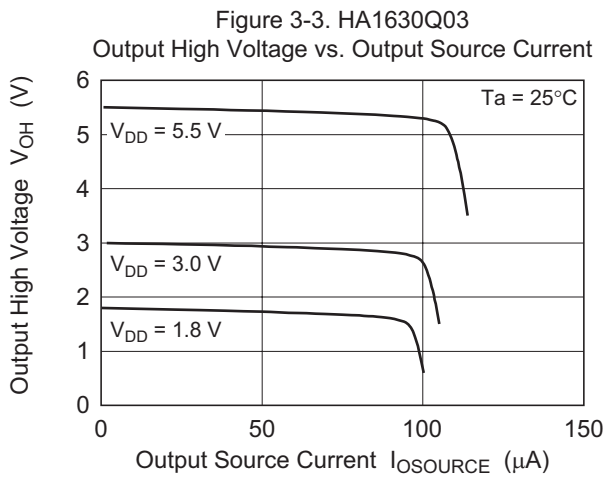
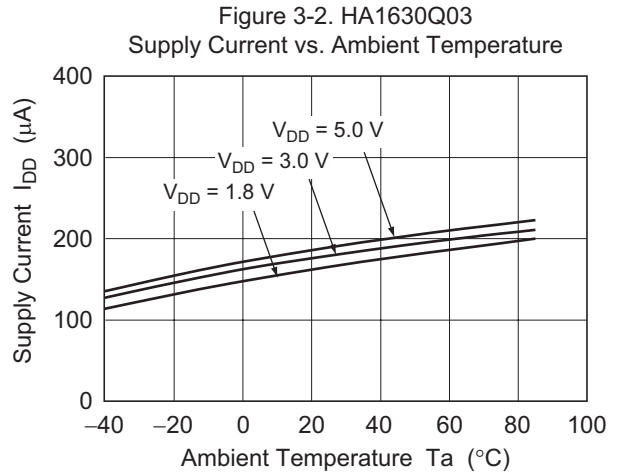
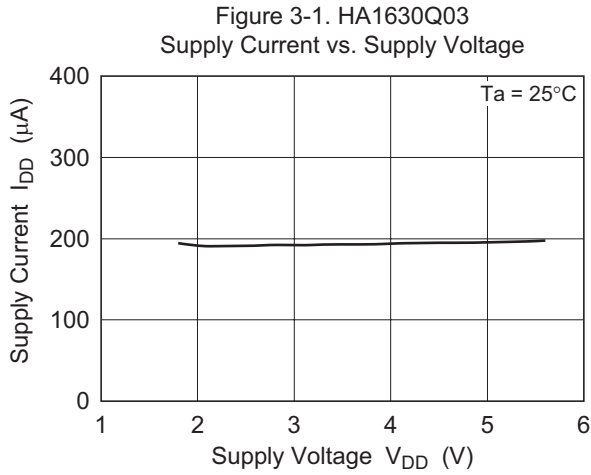


Figure 2-24. HA1630Q02
Voltage Noise Density vs. Frequency



Main Characteristics (HA1630Q03)



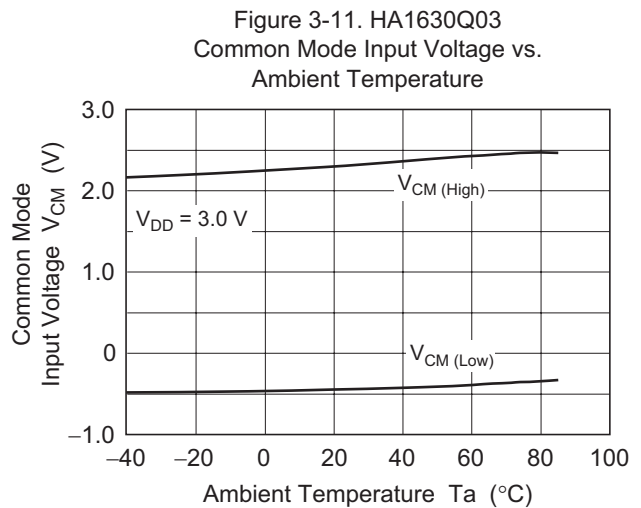
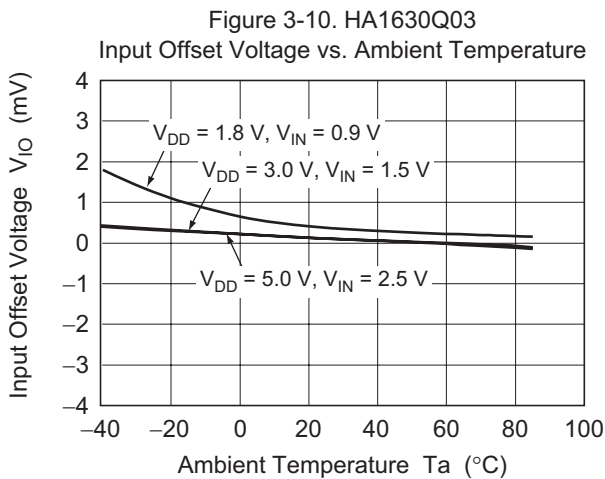
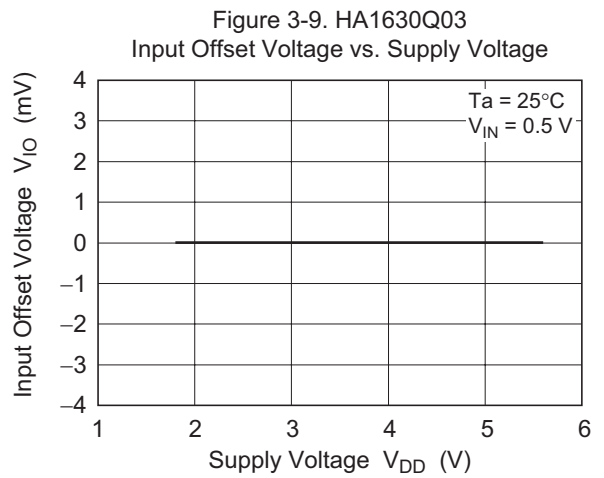
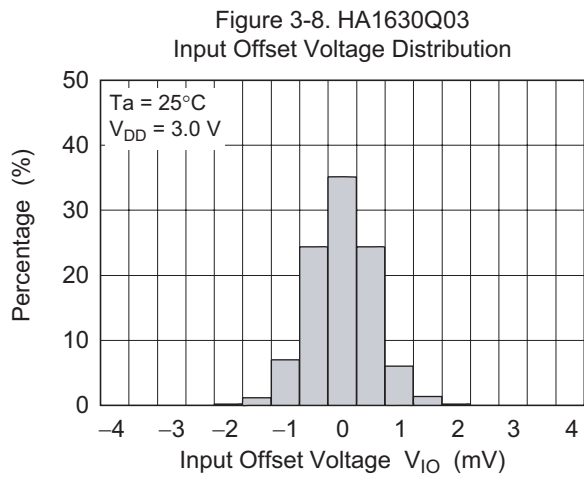
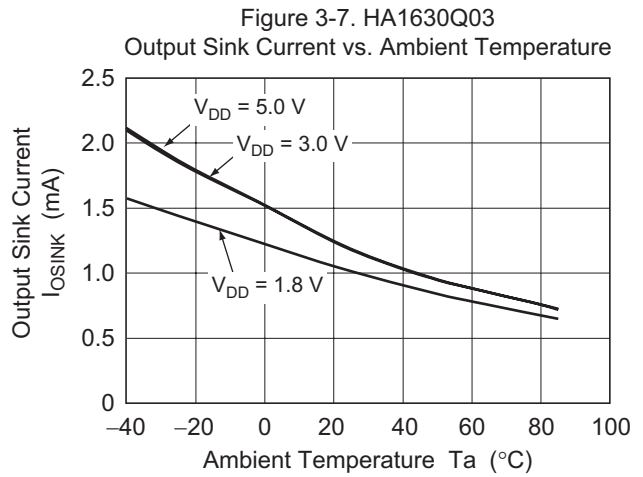
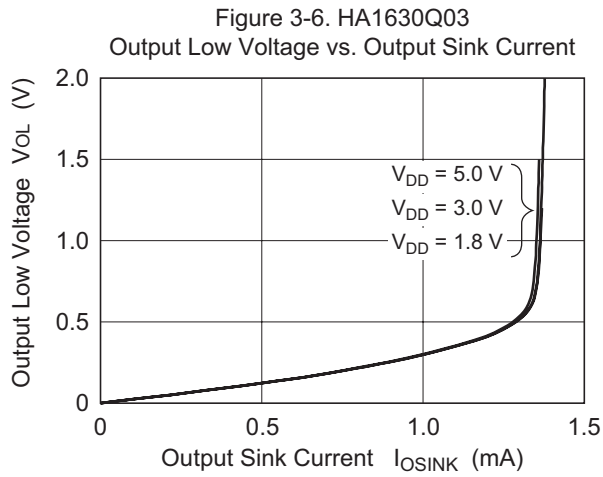


Figure 3-12. HA1630Q03
Power Supply Rejection Ratio vs. Frequency

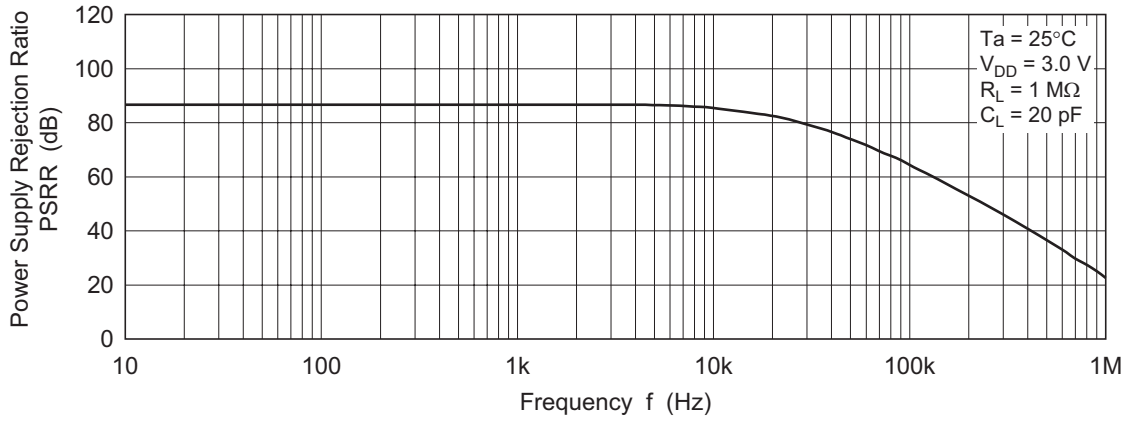


Figure 3-13. HA1630Q03
Common Mode Rejection Ratio vs. Frequency

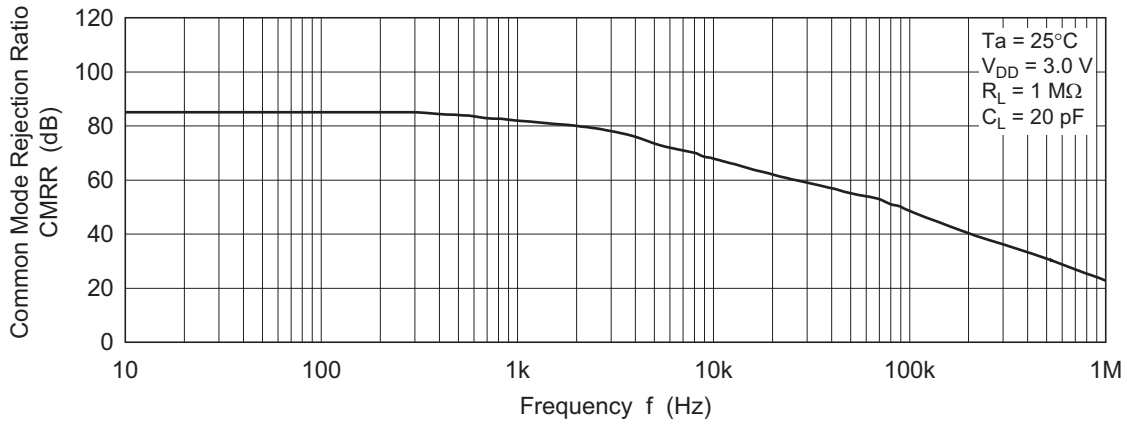
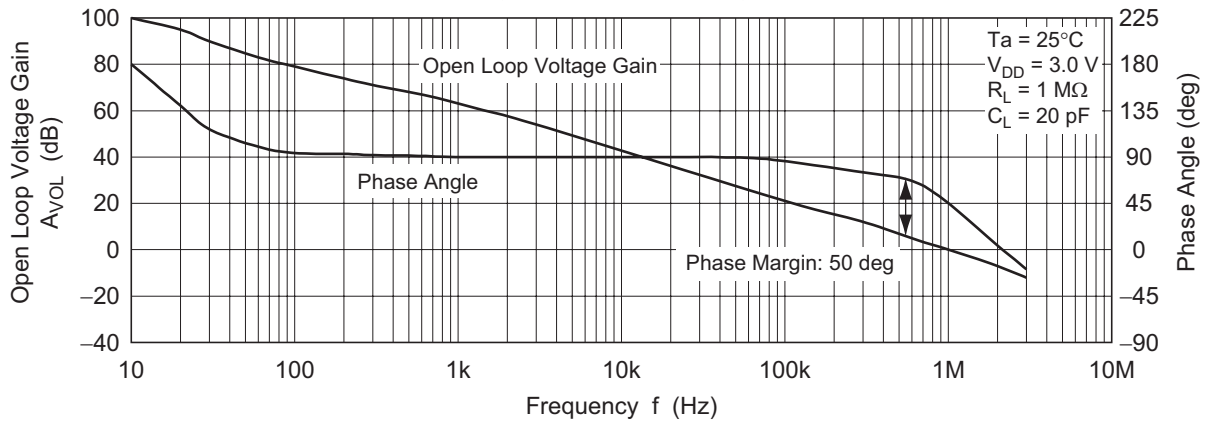


Figure 3-14. HA1630Q03
Open Loop Voltage Gain and Phase Angle vs. Frequency



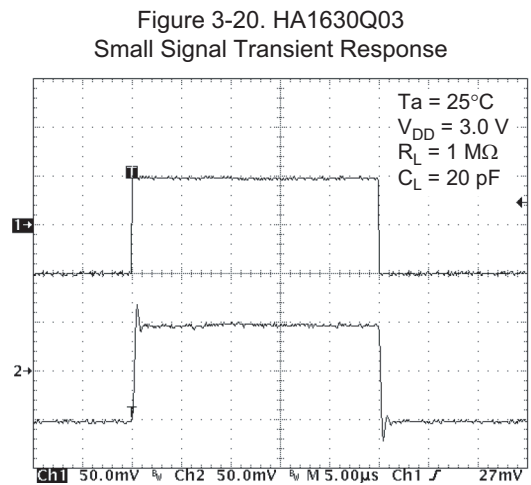
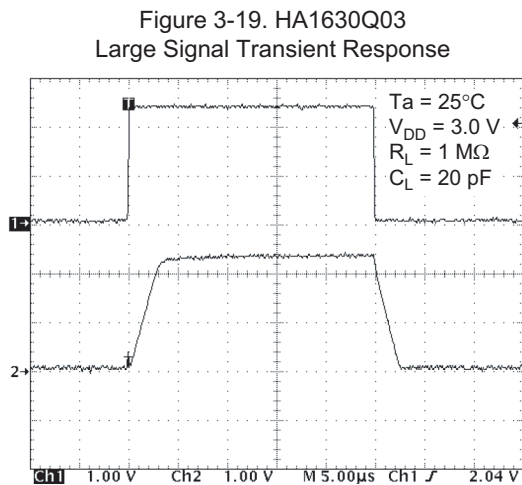
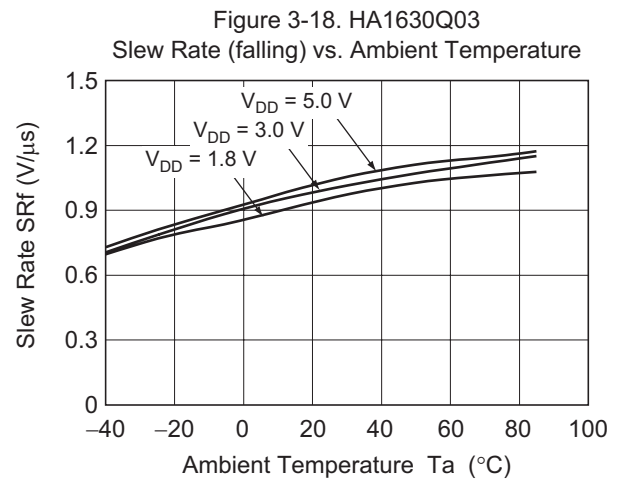
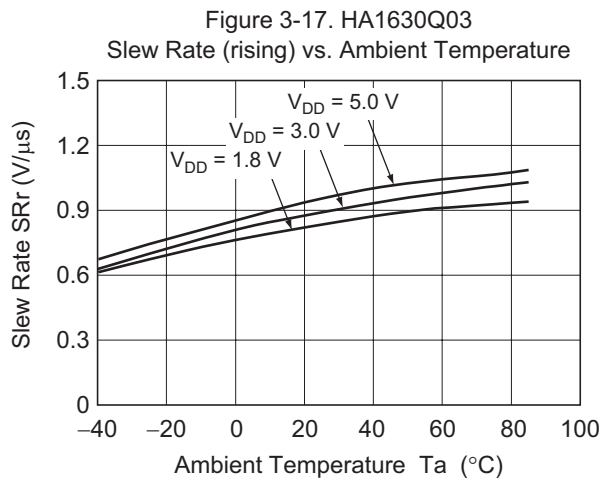
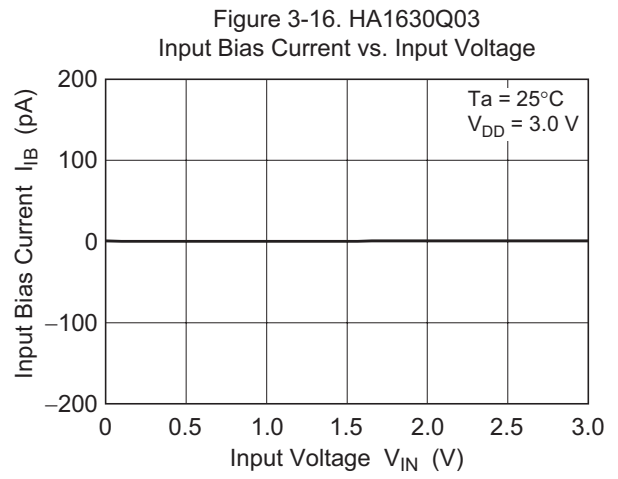
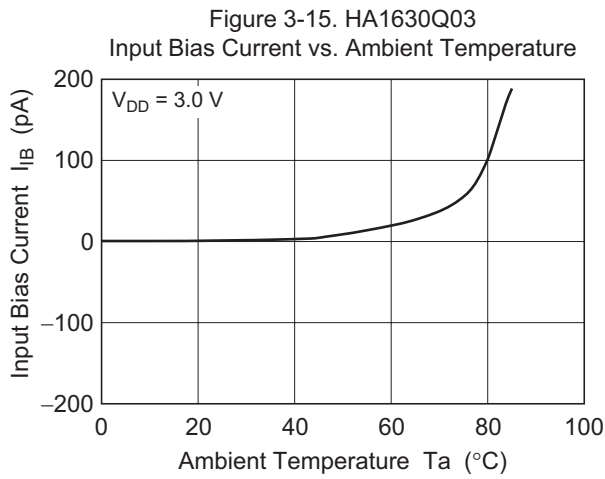


Figure 3-21. HA1630Q03
Total Harmonic Distortion + Noise vs.
Output Voltage p-p

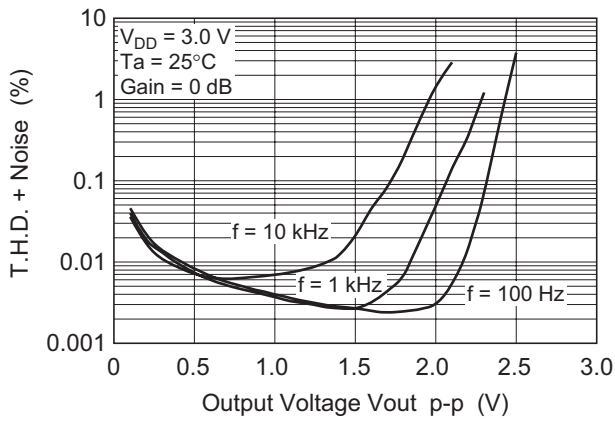


Figure 3-22. HA1630Q03
Total Harmonic Distortion + Noise vs.
Output Voltage p-p

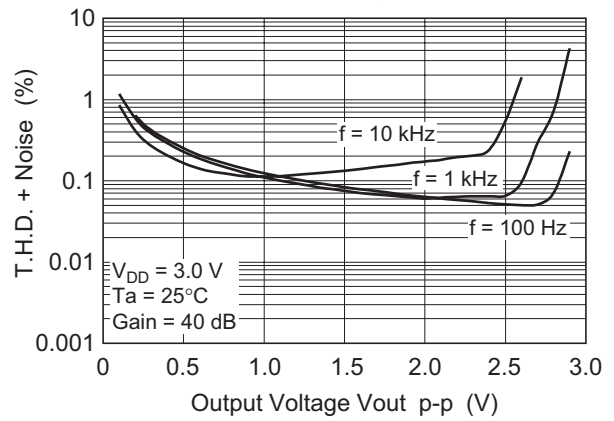


Figure 3-23. HA1630Q03
Voltage Output p-p vs. Frequency

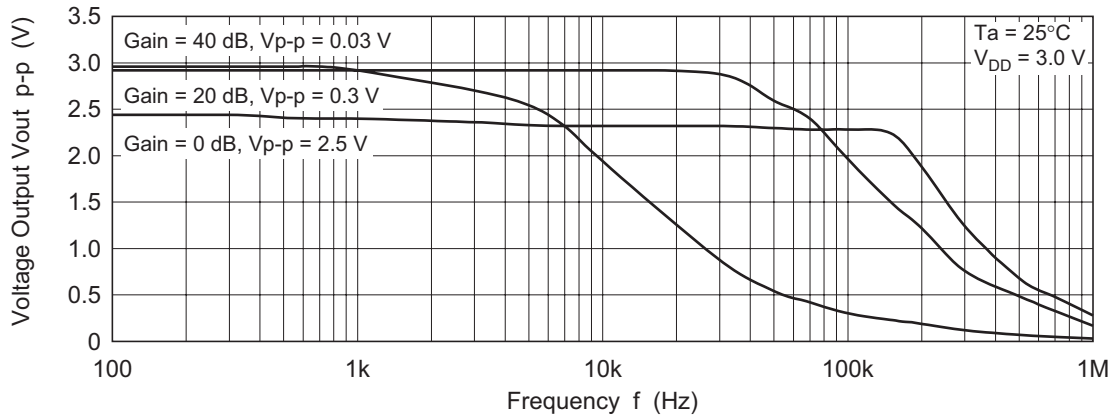
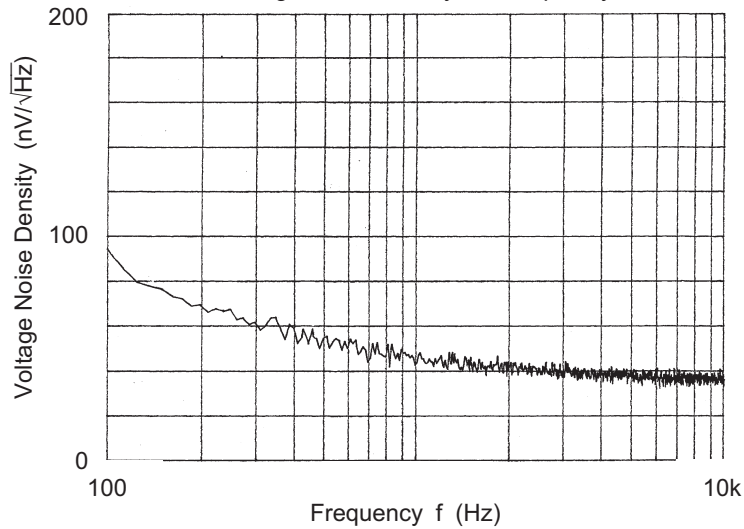
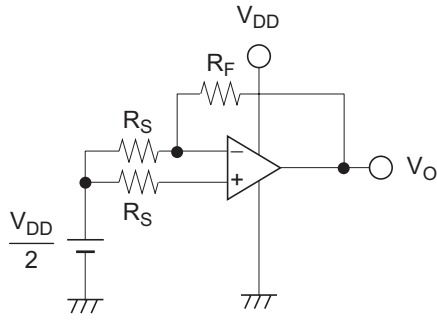


Figure 3-24. HA1630Q03
Voltage Noise Density vs. Frequency



Test Circuits

1. Power Supply Rejection Ratio, PSRR & Voltage Offset, V_{IO}



$$\frac{V_{IO}}{V_{DD}}$$

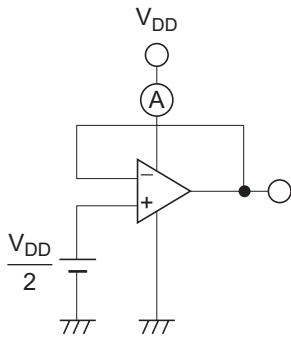
$$V_{IO} = \left(V_O - \frac{V_{DD}}{2} \right) \times \frac{R_S}{R_S + R_F}$$

$$\text{PSRR}$$

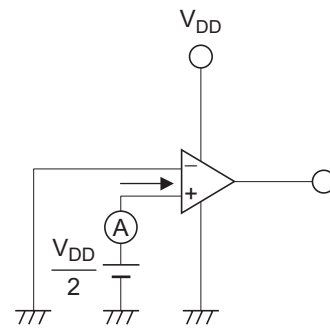
$$\text{PSRR} = -20 \log \left(\left| \frac{V_{O1} - V_{O2}}{V_{DD1} - V_{DD2}} \right| \times \frac{R_S}{R_S + R_F} \right)$$

Measure V_O corresponding to $V_{DD1} = 1.8 \text{ V}$ and $V_{DD2} = 5.5 \text{ V}$

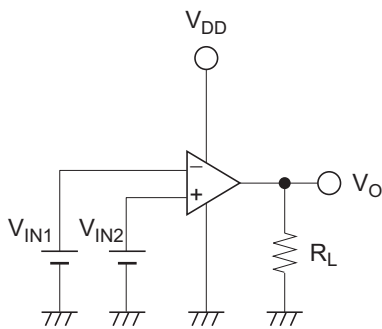
2. Supply Current, I_{DD}



3. Input Bias Current, I_B



4. Output High Voltage, V_{OH}



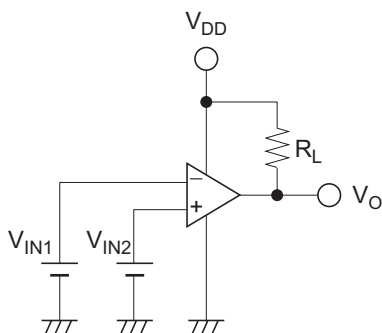
$$\frac{V_{OH}}{V_{DD}}$$

$$R_L = 1 \text{ M}\Omega$$

$$V_{IN1} = V_{DD} / 2 - 0.05 \text{ V}$$

$$V_{IN2} = V_{DD} / 2 + 0.05 \text{ V}$$

5. Output Low Voltage, V_{OL}



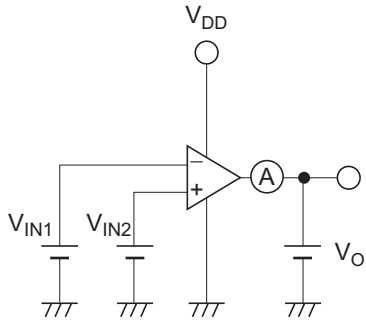
$$\frac{V_{OL}}{V_{DD}}$$

$$R_L = 1 \text{ M}\Omega$$

$$V_{IN1} = V_{DD} / 2 + 0.05 \text{ V}$$

$$V_{IN2} = V_{DD} / 2 - 0.05 \text{ V}$$

6. Output Source Current, $I_{OSOURCE}$ & Output Sink Current, I_{OSINK}



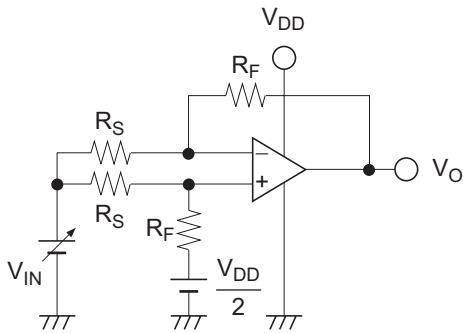
$I_{OSOURCE}$

$$\begin{aligned} V_O &= V_{DD} - 0.5 \text{ V} \\ V_{IN1} &= V_{DD} / 2 - 0.05 \text{ V} \\ V_{IN2} &= V_{DD} / 2 + 0.05 \text{ V} \end{aligned}$$

I_{OSINK}

$$\begin{aligned} V_O &= +0.5 \text{ V} \\ V_{IN1} &= V_{DD} / 2 + 0.05 \text{ V} \\ V_{IN2} &= V_{DD} / 2 - 0.05 \text{ V} \end{aligned}$$

7. Common Mode Input Voltage, V_{CM} & Common Mode Rejection Ratio, CMRR

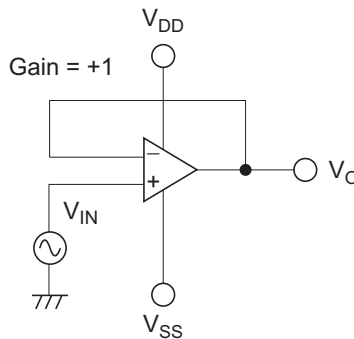
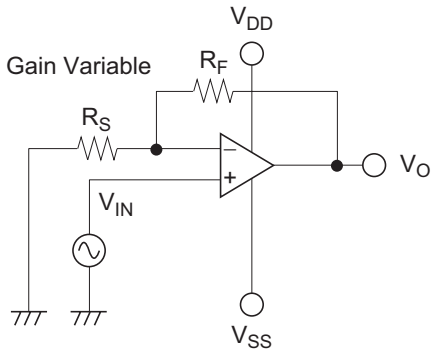


CMRR

$$CMRR = -20 \log \left(\left| \frac{V_{O1} - V_{O2}}{V_{IN1} - V_{IN2}} \right| \times \frac{R_S}{R_S + R_F} \right)$$

Measure V_O corresponding to $V_{IN1} = 0 \text{ V}$ and $V_{IN2} = 2.1 \text{ V}$

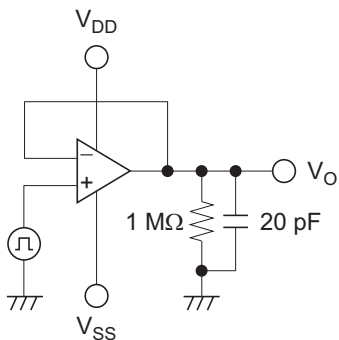
8. Total Harmonic Distortion, THD



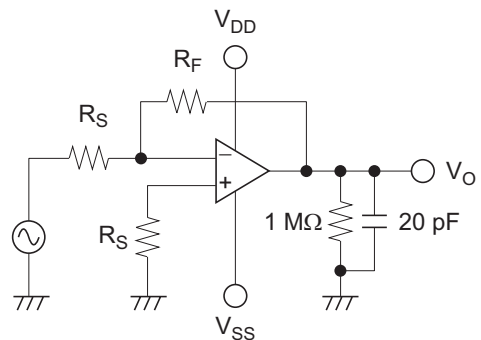
THD

Gain Variable
 $1 + R_F / R_S = 100$
 freq = 100 Hz, 1 kHz, 10 kHz

9. Slew Rate, SR

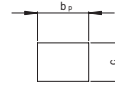
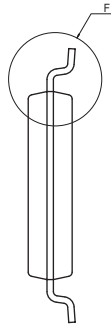
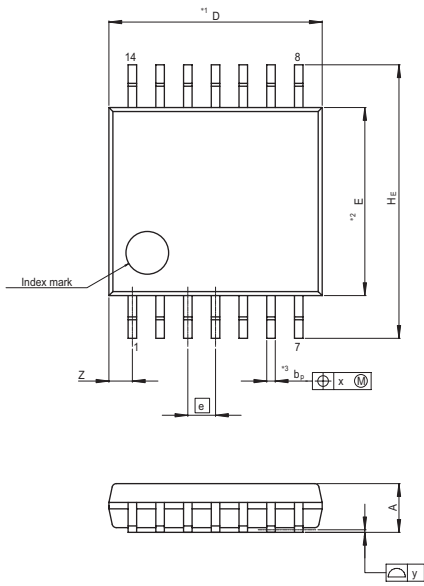


10. Gain, A_V & Phase, GBW

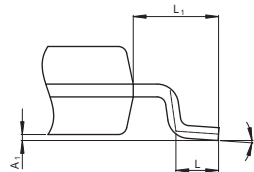


Package Dimensions

| | | | |
|----------------------|--------------|---------------|------------|
| JEITA Package Code | RENESAS Code | Previous Code | MASS[Typ.] |
| P-TSSOP14-4.4x5-0.65 | PTSP0014JA-B | TTP-14DV | 0.05g |



Terminal cross section
(Ni/Pd/Au plating)



Detail F

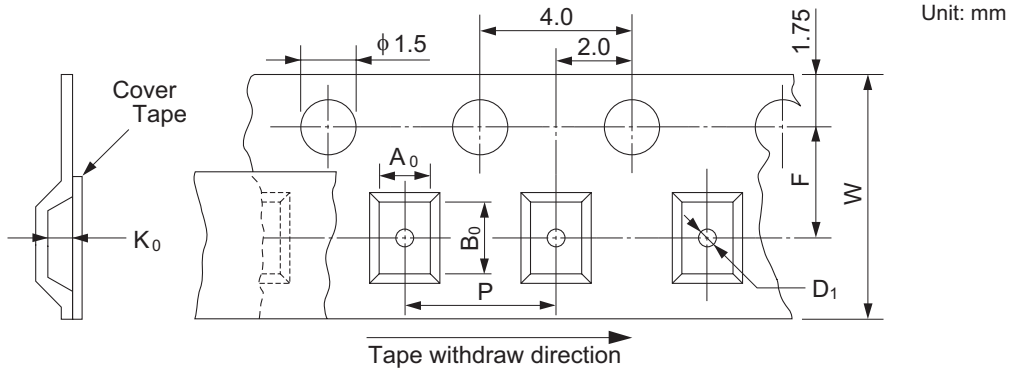
NOTE)
1. DIMENSIONS**1 (Nom)**AND**2*
DO NOT INCLUDE MOLD FLASH.
2. DIMENSION**3*DOES NOT
INCLUDE TRIM OFFSET.

| Reference Symbol | Dimension in Millimeters | | |
|------------------|--------------------------|------|------|
| | Min | Nom | Max |
| D | — | 5.00 | 5.30 |
| E | — | 4.40 | — |
| A ₂ | — | — | — |
| A ₁ | 0.03 | 0.07 | 0.10 |
| A | — | — | 1.10 |
| b _p | 0.15 | 0.20 | 0.25 |
| b ₁ | — | — | — |
| c | 0.10 | 0.15 | 0.20 |
| c ₁ | — | — | — |
| θ | 0° | — | 8° |
| H _E | 6.20 | 6.40 | 6.60 |
| e | — | 0.65 | — |
| x | — | — | 0.13 |
| y | — | — | 0.10 |
| Z | — | — | 0.83 |
| L | 0.4 | 0.5 | 0.6 |
| L ₁ | — | 1.0 | — |

Taping & Reel Specification

[Taping]

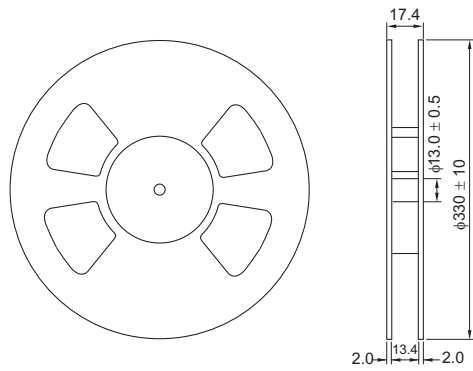
| Package Code | W | P | Ao | Bo | Ko | E | F | D1 | Maximum Storage No. |
|--------------|----|---|-----|-----|-----|---|-----|-----|---------------------|
| TSSOP-14 | 12 | 8 | 6.5 | 5.1 | 1.5 | — | 5.5 | 1.6 | 2,000 pcs/reel |



Unit: mm

[Reel]

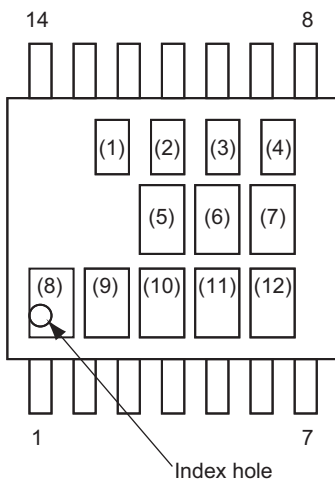
| Package | Tape width | W1 | W2 |
|----------|------------|------|------|
| TSSOP-14 | 12 | 17.4 | 13.4 |



[Ordering Information]

| |
|---------------|
| Ordering Unit |
| 2,000 pcs |

Mark Indication



| | | | |
|------------------------|--------------|------|-----------|
| (1) to (4) | Week code | | |
| (5),(8) to (10) | Space | | |
| (6), (7) (11), (12) | Product Name | 0Q01 | HA1630Q01 |
| | | 0Q02 | HA1630Q02 |
| | | 0Q03 | HA1630Q03 |

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Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (i) placement of substitutive, auxiliary circuits, (ii) use of nonflammable material or (iii) prevention against any malfunction or mishap.

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